Hyperfast Diode 75 A, 1200 V

RHRG75120

Description

The RHRG75120 is a hyperfast diode with soft recovery characteristics. It has the half recovery time of ultrafast diodes and is silicon nitride passivated ionimplanted epitaxial planar construction.

These devices are intended to be used as freewheeling / clamping diodes and diodes in a variety of switching power supplies and other power switching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

Features

- Hyperfast Recovery, $t_{rr} = 100 \text{ ns}$ (@ $I_F = 75 \text{ A}$)
- Max Forward Voltage, $V_F = 3.2 \text{ V}$ (@ $T_C = 25^{\circ}\text{C}$)
- 1200 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- This Device is Pb-Free and is RoHS Compliant

Applications

- Switching Power Supplies
- Power Switching Circuits
- General Purpose

ABSOLUTE MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	1200	V
Working Peak Reverse Voltage	V_{RWM}	1200	V
DC Blocking Voltage	V_{R}	1200	V
Average Rectified Forward Current @ T _C = 42°C	I _{F(AV)}	75	Α
Repetitive Peak Surge Current (Square Wave, 20 kHz)	I _{FRM}	150	Α
Non-Repetitive Peak Surge Current (Halfwave, 1 Phase, 60 Hz)	I _{FSM}	500	Α
Maximum Power Dissipation	P_{D}	190	W
Avalanche Energy (See Figures 7 and 8)	E _{AVL}	50	mJ
Operating and Storage Temperature	T _J , T _{STG}	-65 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

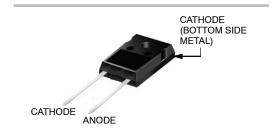
THERMAL CHARACTERISTICS

Parameter	Symbol	Value	Unit
Maximum Thermal Resistance, Junction to Case	$R_{ heta JC}$	0.8	°C/W



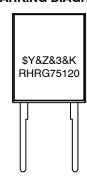
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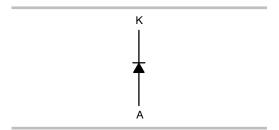


TO-247-2LD CASE 340CL

MARKING DIAGRAM



\$Y &Z &3 &K BHBG75120	 ON Semiconductor Logo Assembly Plant Code Numeric Date Code Lot Code Specific Device Code
RHRG75120	= Specific Device Code
RHRG75120	= Specific Device Code



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

RHRG75120

PACKAGE MARKING AND ORDERING INFORMATION

Device	Device Marking	Package	Shipping
RHRG75120	RHRG75120	TO-247-2L	450 / Tube

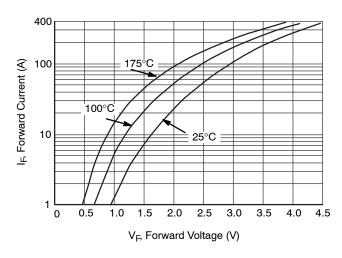
ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
V _F	Instantaneous Forward Voltage (Pulse Width = 300 μs, Duty Cycle = 2%)	I _F = 75 A I _F = 75 A, T _C = 150°C	- -	- -	3.2 2.6	V
I _R	Instantaneous Reverse Current	V _R = 1200 V V _R = 1200 V, T _C = 150°C	- -	- -	250 2	μA mA
T _{rr}	Reverse Recovery Time (See Figure 6), Summation of t_a + t_b	$I_F = 1 \text{ A, } dI_F/dt = 100 \text{ A/}\mu\text{s}$ $I_F = 75 \text{ A, } dI_F/dt = 100 \text{ A/}\mu\text{s}$	- -	- -	85 100	ns
t _a	Time to Reach Peak Reverse Current (See Figure 6)	$I_F = 75 \text{ A}, dI_F/dt = 100 \text{ A}/\mu\text{s}$	-	60	-	ns
t _b	Time from Peak I _{RM} to Projected Zero Crossing of I _{RM} Based on a Straight Line from Peak I _{RM} through 25% of I _{RM} (See Figure 6)	$I_F = 75 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}$	-	25	-	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

RHRG75120

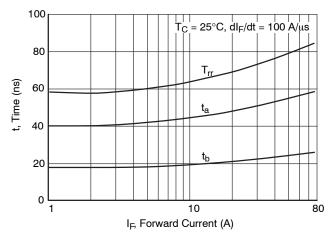
TYPICAL PERFORMANCE CURVES



1000 175°C 100°C 100

Figure 1. Forward Current vs. Forward Voltage

Figure 2. Reverse Current vs. Reverse Voltage





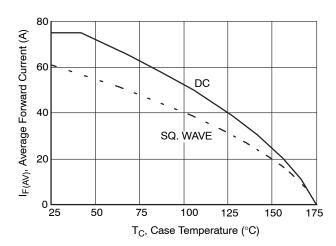
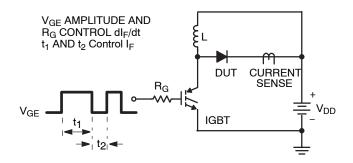


Figure 4. Current Derating Curve

RHRG75120

TEST CIRCUITS AND WAVEFORMS



 $0 \qquad \qquad \begin{array}{c|c} & \frac{dI_F}{dt} & & \\ &$

Figure 5. T_{rr} Test Circuit

Figure 6. T_{rr} Waveforms and Definitions

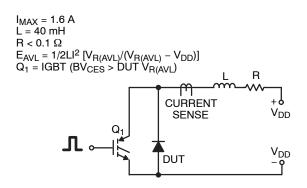


Figure 7. Avalanche Energy Test Circuit

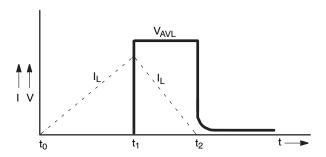
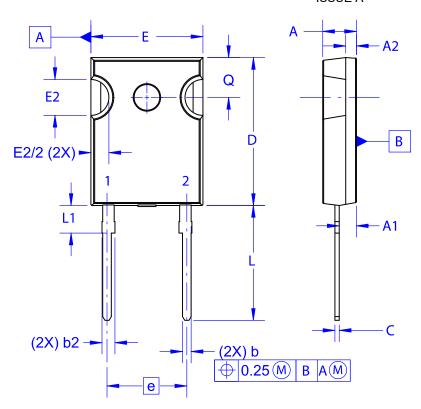


Figure 8. Avalanche Current and Voltage Waveforms

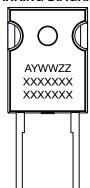
TO-247-2LD CASE 340CL **ISSUE A**





- A. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DRAWING CONFORMS TO ASME Y14.5 2009.
 D. DIMENSION A1 TO BE MEASURED IN THE REGION DEFINED BY L1.
- E. LEAD FINISH IS UNCONTROLLED IN THE REGION DEFINED BY L1.

GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code

= Assembly Location

= Year

WW = Work Week

= Assembly Lot Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

	DATE 03 E	
Ø P —		Ø P1 D2
E1 —	1	D1
,		9

DIM	MIL	MILLIMETERS		
DIM	MIN	NOM	MAX	
Α	4.58	4.70	4.82	
A1	2.29	2.40	2.66	
A2	1.30	1.50	1.70	
b	1.17	1.26	1.35	
b2	1.53	1.65	1.77	
С	0.51	0.61	0.71	
D	20.32	20.57	20.82	
D1	16.37	16.57	16.77	
D2	0.51	0.93	1.35	
Е	15.37	15.62	15.87	
E1	12.81	l	~	
E2	4.96	5.08	5.20	
е	~	11.12	~	
L	15.75	16.00	16.25	
L1	3.69	3.81	3.93	
ØΡ	3.51	3.58	3.65	
Ø P 1	6.61	6.73	6.85	
Q	5.34	5.46	5.58	
S	5.34	5.46	5.58	

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